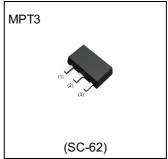


PNP -100mA -400V Middle Power Transistor

Parameter	Value
V_{CEO}	-400V
IC	-100mA

Outline

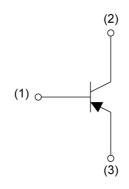


Features

- 1) Complementary NPN Types: 2SCR346P.
- 2) Low V_{CE(sat)}

 $V_{CE(sat)}$ =-400mV(Max.). (I_C/I_B =-20mA/-2mA)

•Inner circuit



- (1) Base
- (2) Collector
- (3) Emitter

Application

LOW FREQUENCY AMPLIFIER

Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
2SAR340P	MPT3	4540	T100	180	12	1000	HA

● Absolute maximum ratings (T_a = 25°C)

Parameter	Symbol	Values	Unit
Collector-base voltage	V_{CBO}	-400	V
Collector-emitter voltage	V _{CEO}	-400	V
Emitter-base voltage	V _{EBO}	-7	V
Calle atom a compart	I _C	-100	mA
Collector current	I _{CP} *1	-200	mA
Base current	I _B	-30	mA
Daniel dia dia dia dia	P _D *2	0.5	W
Power dissipation	P _D *3	2.0	W
Junction temperature	T _j	150	°C
Range of storage temperature	T _{stg}	-55 to +150	°C

● Electrical characteristics (T_a = 25°C)

Darameter	Cumbal	Conditions	Values			Unit
Parameter	Symbol Conditions —		Min.	Тур.	Max.	Offic
Collector-base breakdown voltage	BV _{CBO}	I _C = -100μA	-400	1	-	V
Collector-emitter breakdown voltage	BV _{CEO}	I _C = -1mA	-400	1	-	V
Emitter-base breakdown voltage	BV _{EBO}	I _E = -100μA	-7	ı	-	٧
Collector cut-off current	I _{CBO}	V _{CB} = -400V	ı	1	-10	μA
Emitter cut-off current	I _{EBO}	V _{EB} = -6V	ı	1	-10	μA
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = -20 \text{mA}, I_B = -2 \text{mA}$	ı	-150	-400	mV
DC current gain	h _{FE}	$V_{CE} = -10V, I_{C} = -10mA$	82	1	270	-
Output capacitance	C _{ob}	V _{CB} = -10V, I _E = 0A, f = 1MHz	-	15	-	pF

hFE values are calssified as follows:

rank	Р	Q	-	-	-
h _{FE}	82 - 180	120 - 270	-	-	-

- *1 Pw=10ms Single Pulse
- *2 Each terminal mounted on a reference land.
- *3 Mounted on a ceramic board.(40×40×0.7mm)

● Electrical characteristic curves(T_a = 25°C)

Fig.1 Grounded Emitter Propagation Characteristics

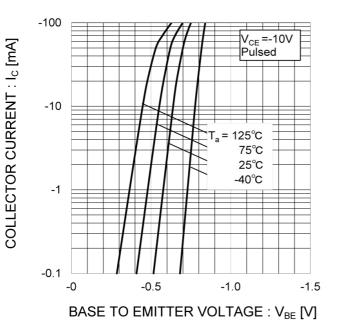
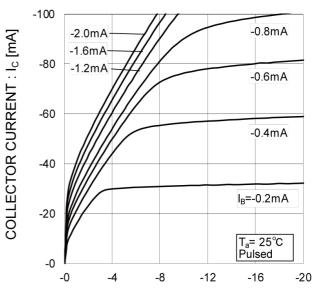


Fig.2 Typical Output Characteristics



COLLECTOR TO EMITTER VOLTAGE: VCE [V]

Fig.3 DC Current Gain vs. Collector Current(I)

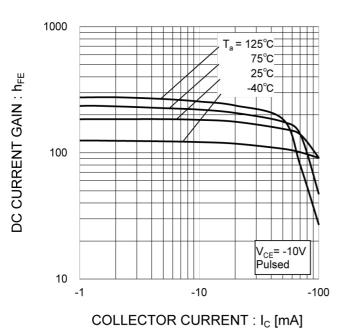
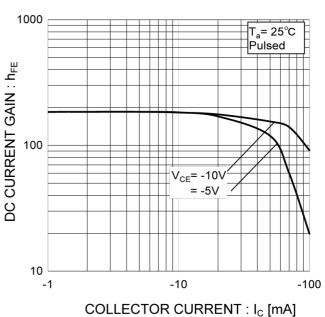


Fig.4 DC Current Gain vs. Collector Current(II)



● Electrical characteristic curves(T_a = 25°C)

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current(I)

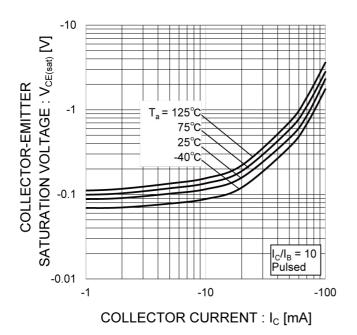


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current(II)

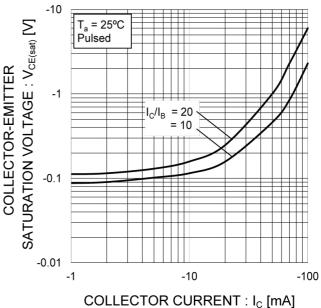


Fig.7 Base-Emitter Saturation Voltage vs. Collector Current

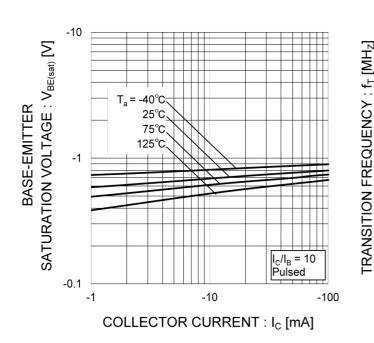
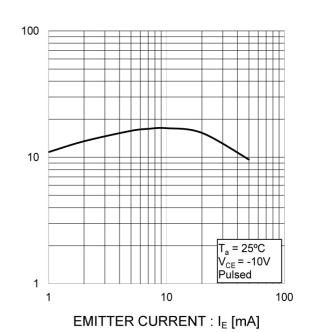


Fig.8 Gain Bandwidth Product vs. Emitter Current



● Electrical characteristic curves(T_a = 25°C)

Fig.9 Emitter input capacitance vs. Emitter=Base Voltage Collector output capacitance vs. Collector-Base Voltage

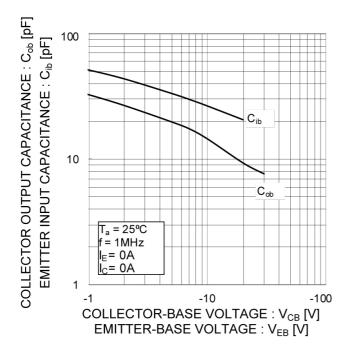
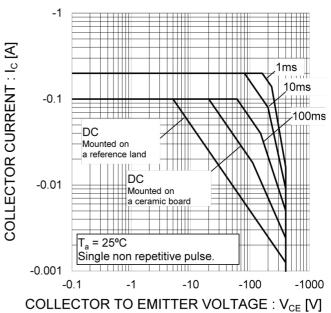
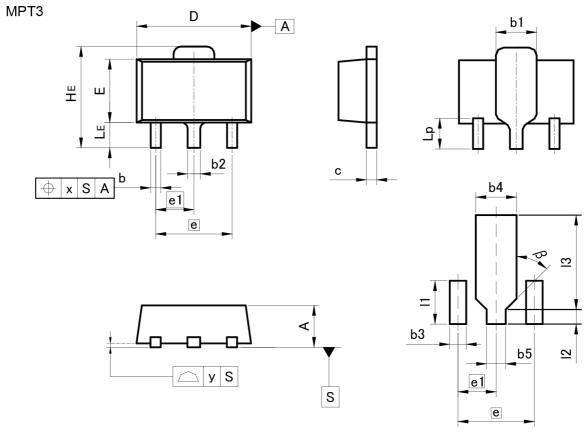


Fig.10 Safe Operating Area



Dimensions



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

	MILIMETERS		INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	1.40	1.50	0.055	0.059	
b	0.30	0.50	0.012	0.020	
b1	1.50	1.70	0.059	0.067	
b2	0.40	0.60	0.016	0.024	
С	0.35	0.50	0.014	0.020	
D	4.40	4.70	0.173	0.185	
E	2.40	2.70	0.094	0.106	
е	3.00		0.118		
e1	1.5	50	0.059		
HE	3.70	4.30	0.146	0.169	
LE	0.80	1.20	0.031	0.047	
Lp	1.01	1.41	0.040	0.056	
х	-	0.15	=	0.006	
У	_	0.10	_	0.004	

DIM	DIM MILIMETERS MIN MA		INCHES		
DIM			MIN	MAX	
b3	_	0.65	ı	0.026	
b4	_	1.70	ı	0.067	
b5	_	0.75	ı	0.030	
l1	_	1.71	ı	0.067	
12	-	0.58	-	0.023	
13	_	3.72	-	0.146	
β	45°		45	0	

Dimension in mm/inches



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2SAR340P - Web Page

Distribution Inventory

Part Number	2SAR340P
Package	MPT3
Unit Quantity	1000
Minimum Package Quantity	1000
Packing Type	Taping
Constitution Materials List	inquiry
RoHS	Yes

Mouser Electronics

Authorized Distributor

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ROHM Semiconductor: 2SAR340PT100Q

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